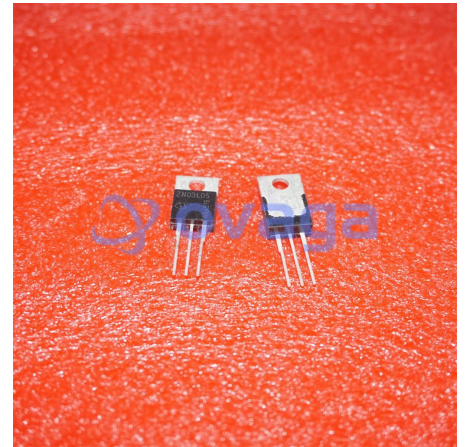


OptiMOS Power-Transistor (MOS power transistors) ,MOSFET N-KANAL POWER MOS

Manufacturers	Infineon Technologies Corporation
Package/Case	TO-220AB
Product Type	Transistors
RoHS	Rohs
Lifecycle	



Images are for reference only

Please submit RFQ for SPP80N03S2L-05 or [Email to us: sales@ovaga.com](mailto:sales@ovaga.com) We will contact you in 12 hours.

[RFQ](#)

General Description

SPP80N03S2L-05 is a specific model of power MOSFET (metal-oxide-semiconductor field-effect transistor) manufactured by Infineon Technologies AG.

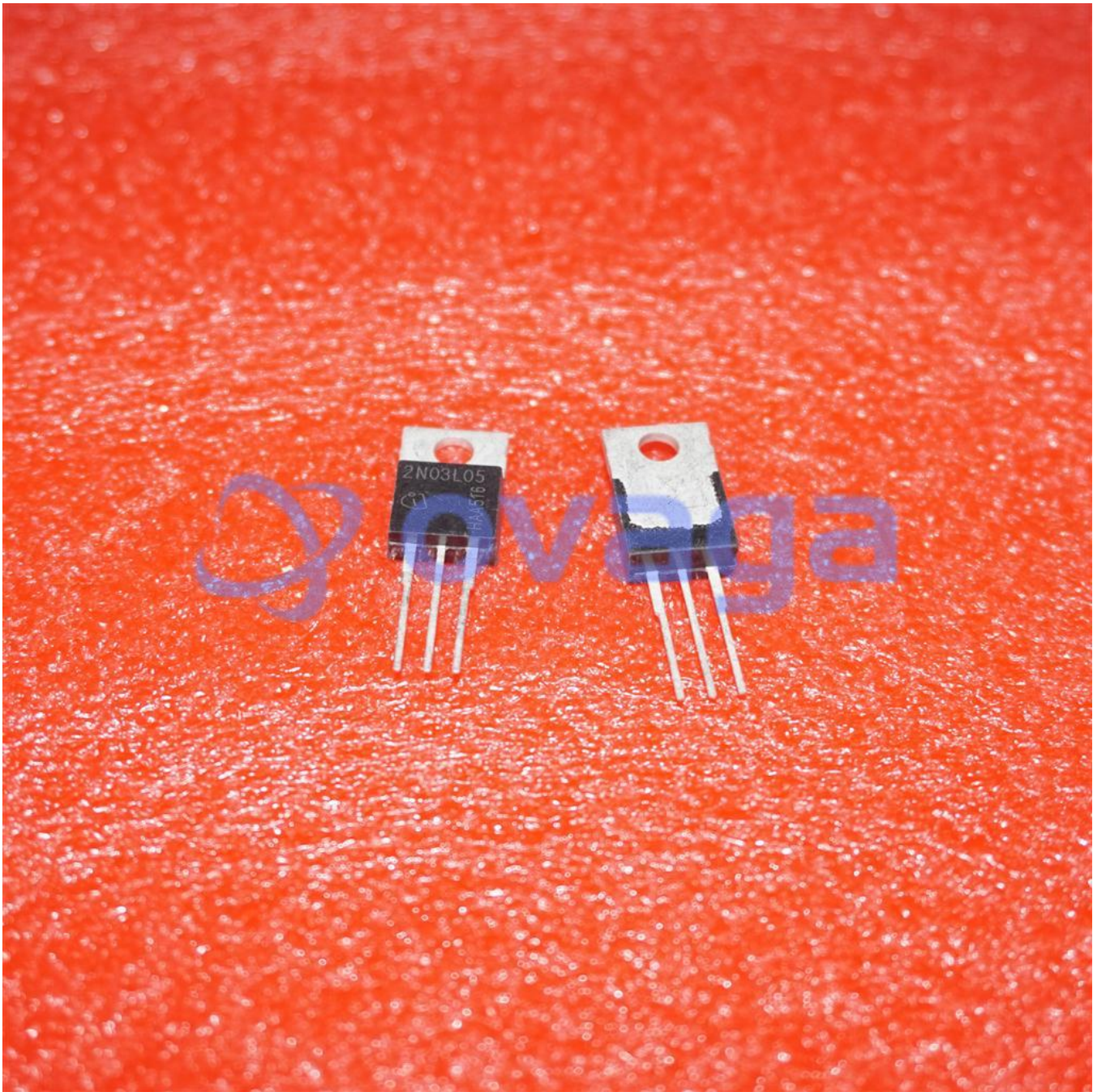
Features

It is an N-channel MOSFET with a maximum drain-source voltage (VDS) of 30V.

It has a maximum continuous drain current (ID) of 80A and a low on-resistance (RDS(on)) of 5.5 milliohms.

It can operate at a maximum junction temperature of 175°C.

It comes in a TO-220 package.



Related Products



[BSP613P](#)

Infineon Technologies Corporation
SOT-223



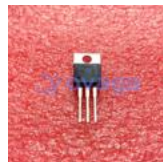
[SPP11N65C3](#)

Infineon Technologies Corporation
TO-220



[SPP07N65C3](#)

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